

LA7411,7411M

Playback Amplifier and Record Amplifier for VHS VCRs

Overview

The LA7411 and LA7411M are playback and record amplifier IC for two-head VHS VCRs. When used in conjunction with the video signal processing ICs of the LA7420/30 series, it is possible to eliminate the need to adjust the Y/C record current.

Functions

- 2-channel playback amplifier.
- 1-channel record amplifier.
- · REC/PB mode switching head switch circuit.
- Envelope wave detection (for auto-tracking).

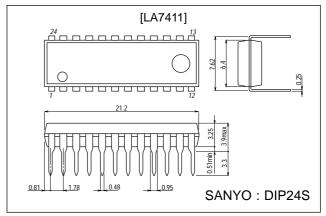
Features

- The record amplifier provides stable record characteristics in constant current drive mode, which is able to withstand load fluctuations. In addition, the built-in AGC eliminates the need to adjust the record current.
- Designed to share printed circuit boards with the LA7416/7416M (for 4-head systems).

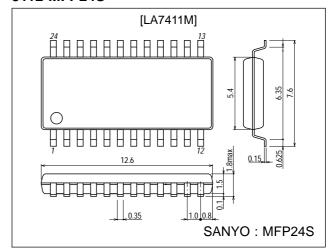
Package Dimensions

unit: mm

3067-DIP24S



3112-MFP24S



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Specifications

Maximum Ratings at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		7.0	V
Allowable power dissipation	Pd max	Ta ≤65 °C	700	mW
	Fu illax	1a ≧05 °C	*500	mW
Operating temperature	Topr		-10 to +65	∘C
Storage temperature	Tstg		-40 to +150	∘C

^{*:} LA7411M Pd max value which represents the value when mounted on the board.

Operating Conditions at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit		
Recommended supply voltage	V _{CC}		5.0	V		
Operating supply voltage range	V _{CC} op		4.8 to 5.5	V		

Electrical Characteristics at Ta = 25 °C

Parameter		Symbol	Input	Output	Conditions	T1	T2	min	typ	max	Unit
[PB Mode]					T12: 5.0 V T10: Open	EP/SP	SW30 MUTE				
					T4: Open (PB)						
Current consumption		I _{CCP}			Pin 12 input current		0	14	18	22	mA
Voltage gain L	CH1	G _{VP1}	T17A	T7A	V _I = 38 mVp-p		0	56.5	59.5	62.5	dB
Voltage gain H	CH2	G _{VP2}	T20A	T7A	f = 1 MHz		2.5	56.5	59.5	62.5	dB
Voltage gain difference		ΔG_{VP1}			G _{VP1} — G _{VP2}			-1	0	+1	dB
Equivalent input	CH1	V _{NIN} 1	T17A	T7A	After 1.1 MHz		0		1.1	1.5	μVrms
noise voltage	CH2	V _{NIN} 2	T20A	T7A	V _{OUT} /G _{VP1,2}		2.5		1.1	1.5	μVrms
Frequency characteristics	CH1	ΔVfp1	T17A	T7A	$V_I = 38 \text{ mVp-p},$ f = 7 MHz		0	-2.5	+1		dB
	CH2	ΔVfp2	T20A	T7A	V _{OUT} /G _{VP1,2} output ratio		2.5	-2.5	+1		dB
harmonic distortion	CH1	V _{HDP} 1	T17A	T7A	V _I = 38 mVp-p, f = 4 MHz 8 M component		0		-40	-35	dB
	CH2	V _{HDP} 2	T20A	T7A	4 M component output ratio		2.5		-40	-35	dB
Maximum output level	CH1	V _{OMP} 1	T17A	T7A	f = 1 MHz Output level when		0	1.0	1.2		Vp-p
	CH2	V _{OMP} 2	T20A	T7A	tertiary distortion of the output is -30 dB		2.5	1.0	1.2		Vp-p
Cross-talk (Note 1)	CH1	V _{CR} 1	T20A	T7A	$V_I = 38 \text{ mVp-p},$ f = 4 MHz		0		-40	-35	dB
(1515-1)	CH2	V _{CR} 2	T17A	T7A	V _{OUT} /G _{VP1,2} output ratio		2.5		-40	-35	dB
Output DC offset		ΔV _{ODC} 1		T7	CH1-CH2		0	-100	0	+100	mV
							2.5				
Envelope wave detection output pin voltage		V _{ENV}		T5	T5 DC voltage with no input	0	0	0	0.8	1.5	V
Envelope wave detection voltage SP1		V _{ENVSP} 1	T17A	T5	f = 4 MHz, T7A: Adjusted to 175 mVp-p	0	0	2.0	2.5	3.0	V
Envelope wave detection voltage SP2		V _{ENVSP} 2	T17A	T5	f = 4 MHz, T7A: Adjusted to 450 mVp-p	0	0	4.5	4.8	5.0	V
Envelope wave detection voltage EP1		V _{ENVEP} 1	T17A	T5	f = 4 MHz, T7A: Adjusted to 125 mVp-p	5.0	0	2.0	2.5	3.0	V

Note 1: Status where input stage L (8.2 $\mu H)$ is shorted

"*" represents output pins.

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Electrical Characteristics at Ta = 25 °C

Parameter	Symbol	Input	Output	Conditions	T10	T2	min	typ	max	Unit
Envelope wave detection voltage	V _{ENVEP} 2	T17A	T5	f = 4 MHz,	5.0	0	4.5	4.8	5.0	V
EP2	VENVEP2	IIIA	15	T7A: Adjusted to 350 mVp-p	3.0		4.5	4.0	3.0	v
ON resistance of SW-Tr which is	R _{PON} 14		P-14	DC difference				4.0	6.0	Ω
turned ON in PB mode	1011			measured for 1						
				mA, 2 mA						
				current inflow						
Threshold level EP/SP	EPS-1		T1	$SP \rightarrow EP$	*		1.7		5.0	V
	EPS-2		T1	$EP \to SP$	*		0.0		1.3	V
Threshold level SW30	SW30-1		T2	Lch → Hch		*	1.2		5.0	V
	SW30-2		T2	Hch → Lch		*	0.0		0.8	V
[REC Mode]				T12: 5.0 V	REC	SW30				
[Final mess]				T3: 5.0 V	Adj2	MUTE				
				T4: 5.0 V(REC)	,_					
Current consumption	I _{CCP}			Pin 12	Open	0	38	46	54	mA
	CCP			input c urrent	-					
REC AGC	V _R	T8A	T18A	f = 4 MHz	Open	0	116	123	130	mVp-p
Amp output level	- K			$V_I = 200 \text{ mVp-p}$	-					
AGC Amp	ΔV _{AGC} 1	T8A	T18A	f = 4 MHz,	Open	0		0.5	1.0	dB
control characteristics 1	_ AGC .		1.071	$V_{I} = 400 \text{ mVp-p}$	0,000			0.0		
				Output level/						
				V _{RSP, EP} ratio						
AGC Amp	ΔV _{AGC} 2	T8A	T18A	f = 4 MHz,	Open	0	-1.0	-0.5		dB
control characteristics 2	7.00			$V_{I} = 100 \text{ mVp-p}$						
				Output level/						
				V _{RSP, EP} ratio						
AGC Amp	ΔV_{FR}	T8A	T18A	f = 1 M, 7 MHz	Open	0	-4.0	-3.0	-2.0	dB
frequency characteristics (Note 2)				$V_I = 200 \text{ mVp-p}$						
				7 MHz/1 MHz,						
1001		To 4	T404	output ratio				45	40	- ID
AGC Amp	ΔV_{HDR}	T8A	T18A	f = 4 MHz,	Open	0		-45	-40	dB
secondary harmonic level				V _I = 200 mVp-p 8 M component						
				l — — —						
				4 M component						
ACC A	41/	Το Δ	T40A	output ratio	۸ ا:	0	200	00		^
AGC Amp maximum output level (Note 3)	$\Delta V_{\sf OMR}$	T8A	T18A	f = 4 MHz,	Adj.	0	20	22		mAp-p
maximum output lever (Note 3)				output level when secondary						
				distortion of the						
				output is -35 dB						
AGC Amp	ΔV_{MR}	T8A	T18A	f = 4 MHz,	Open	5.0		-45	-40	dB
mute attenuation	→ MR	10/1	110/	$V_{I} = 200 \text{ mVp-p}$	Open	0.0		-75	-10	٥٥
				Output level/						
				V _{RSP, EP} ratio						
REC	ΔV_{CY}	T7A	T18A	T6A: f = 629 kHz,	Open	0		-45	-40	dB
AGC Amp				$V_{I} = 360 \text{ mVp-p}$						
mixed modulation relative level				T7A: f = 4 MHz,						
		T8A	T18A	$V_{I} = 200 \text{ mVp-p}$	Open	0		-45	-40	dB
				(4 M±629 k)/4 M output ratio						
ON resistance of SW-Tr which is	D. 47		P-17	DC difference				4.0	6.0	
turned ON in REC mode	R _{RON} 17		17-17	measured for				4.0	0.0	Ω
turned ON III REC IIIOGE	D. 30		P-20	1 mA, 2 mA		-		4.0	6.0	Ω
	R _{RON} 20		F-20	current inflow				4.0	0.0	32
DEC MUTE throoked devel	MUTE-1		T2	MUTE OFF →		*	3.4		5.0	V
REC MUTE threshold level	IVIU I E-T		12	MUTE OFF →			3.4		5.0	V
	MUTEO		T2	MUTE ON →	-	*	0.0		3.0	V
	MUTE-2		12	OFF			0.0		ა.0	V
REC/PB threshold level	SW			T4: Control			2.2		5.0	V
NEC/FD uneshold level	REC/PB			voltage			2.2		5.0	v
	NEC/FD			voitage						

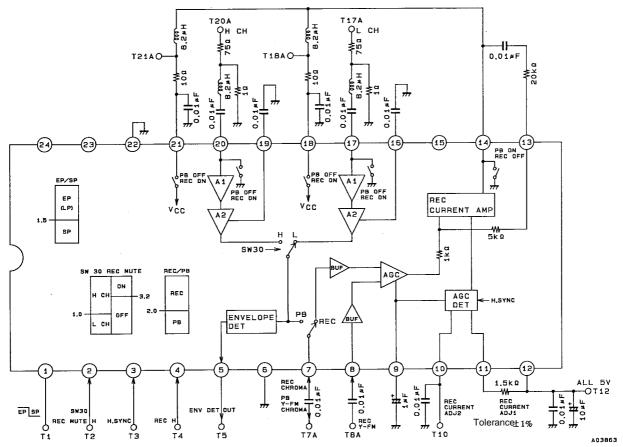
Note 2: Apply approximately 1.8 V DC to the AGC wave detection filter pin (pin 9) and fix the amplifier gain for measurement.

Note 3: Apply DC voltage to T10 (REC CUR. ADJ2) and adjust the output level.

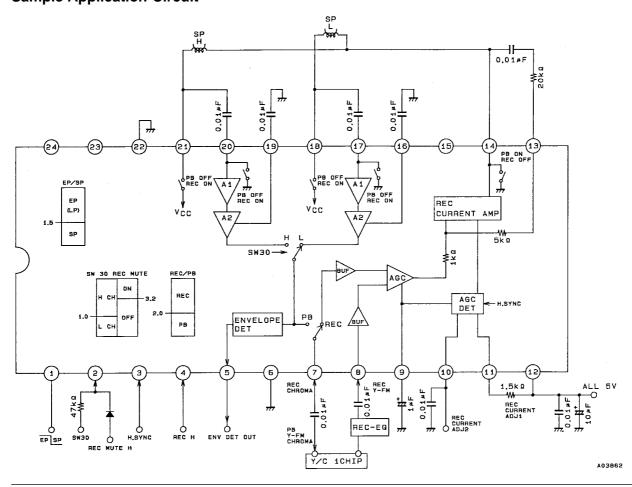
Note: Use a resistor with a tolerance of \pm 1.0% between pins 11 and 12.

[&]quot;*" represents output pins.

Test Circuit Diagram



Sample Application Circuit



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